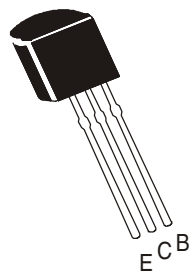


NPN SILICON PLANAR EPITAXIAL TRANSISTOR

CSC1845



TO-92
Plastic Package

For use as the middle range Amplifier in Hi-Fi and other similar Amplifier Applications

ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V_{CEO}	120	V
Collector Base Voltage	V_{CBO}	120	V
Emitter Base Voltage	V_{EBO}	5	V
Base Current	I_B	10	mA
Collector Current	I_C	50	mA
Power Dissipation @ $T_a=25^\circ\text{C}$	P_C	500	mW
Junction Temperature	T_j	+125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 125	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Cut off Current	I_{CBO}	$V_{CB} = 120\text{V}, I_E = 0$			50	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 5.0\text{V}, I_C = 0$			50	nA
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$			0.30	V
Base Emitter On Voltage	$V_{BE(on)}$	$V_{CE} = 6.0\text{V}, I_C = 1.0\text{mA}$	0.55		0.65	V
DC Current Gain	h_{FE}	$V_{CE} = 6.0\text{V}, I_C = 0.1\text{mA}$	150			
	$*h_{FE}$	$V_{CE} = 6.0\text{V}, I_C = 1.0\text{mA}$	200		1200	
Transition Frequency	f_T	$V_{CE} = 6.0\text{V}, I_C = 1.0\text{mA}$	50			MHz
Output Capacitance	C_{ob}	$V_{CB} = 30\text{V}, I_E = 0, f = 1.0\text{MHz}$			2.5	pF
Noise Voltage	NV	$V_{CE} = 5.0\text{V}, I_C = 1.0\text{mA}, R_G = 100\text{k}\Omega$ $G_V = 80\text{dB}, f = 10\text{Hz to } 1.0\text{KHz}$			40	mV

$*h_{FE}$ Classifications

P : 200 - 400

F : 300 - 600

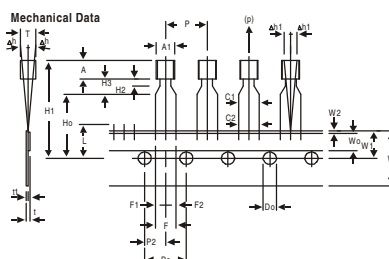
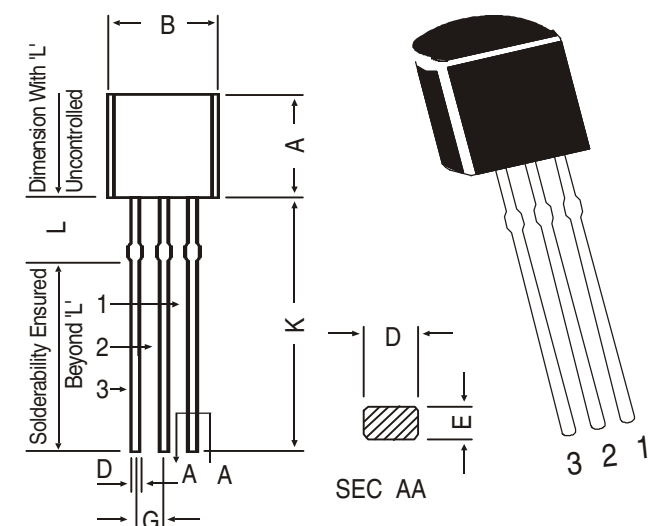
E : 400 - 800

U : 600 - 1200

TO-92 Plastic Package

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TO-92 Transistors on Tape and Ammo Pack



All dimensions in mm

ITEM	SYMBOL	SPECIFICATION				REMARKS
		MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.0		4.8		CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH
BODY HEIGHT	A	4.8		5.2		
BODY THICKNESS	T	3.9		4.2		
PITCH OF COMPONENT	P	12.7		± 1.0		
FEED HOLE PITCH	Po	12.7		± 0.3		TO BE MEASURED AT BOTTOM OF CLINCH
FEED HOLE CENTRE TO COMPONENT CENTRE	P2	6.35		± 0.4		
DISTANCE BETWEEN OUTER LEADS	F	5.08		+ 0.6 - 0.2		
COMPONENT ALIGNMENT SIDE VIEW	Δh	0	1.0			
COMPONENT ALIGNMENT FRONT VIEW	Δh1	0	1.3			AT TOP OF BODY AT TOP OF BODY
TAPE WIDTH	W	18		± 0.5		
HOLD-DOWN TAPE WIDTH	Wo	6		± 0.2		
HOLE POSITION	W1	9		+ 0.7 - 0.5		
HOLD-DOWN TAPE POSITION	W2	0.5		± 0.2		t1 0.3-0.6
LEAD WIRE CLINCH HEIGHT	Ho	16		± 0.5		
COMPONENT HEIGHT	H1	23.25		11.0		
LENGTH OF SNIPPED LEADS	L					
FEED HOLE DIAMETER	Do	4		± 0.2		
TOTAL TAPE THICKNESS	t		1.2			
LEAD - TO - LEAD DISTANCE	F1, F2	2.54		+ 0.4 - 0.1		
STAND OFF	H2	0.45		1.45		
CLINCH HEIGHT	H3			3.0		
LEAD PARALLELISM	C1 - C2			0.22		
PULL - OUT FORCE	(P)	6N				

NOTES

- Maximum alignment deviation between leads will not be greater than 0.2mm.
- Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
- Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
- There will be no more than three (3) consecutive missing components in a tape.
- A tape trailer, having at least three feed holes are provided after the last component in a tape.
- Splices should not interfere with the sprocket feed holes.

DIM	MIN.	MAX.
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.41	0.55
E	0.35	0.50
F	5 DEG	
G	1.14	1.40
H	1.14	1.53
K	12.70	—
L	1.982	2.082

All dimensions in mm.

PIN CONFIGURATION

1. BASE
2. COLLECTOR
3. EMITTER

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

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